## NSN 5961-01-253-3418

Diode Semiconductor Device - Page 1 of 1



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Function For Which Designed:
Transient suppressor
Mounting Method:
Terminal
Criticality Code Justification:
Feat
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
33.9 breakdown voltage, dc and 38.2 breakdown voltage, dc
Current Rating Per Characteristic:
30.00 milliamperes drain current nanoamperes
Special Features:
Nuclear hardness critical item; junction pattern arrangement: pn
Nuclear Hardness Critical Feature:
Hardened
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0